1.0 General Description

The AMIS-710324-A4 (PI324MC-A4) is a contact image sensor (CIS) module. It is a dual-analog-output contact image sensor, using MOS image sensor technology for high-speed performance and high sensitivity. The AMIS-710324-A4 is suitable for scanning A4 size (216mm) documents with 11.8 dots per millimeter (dpm) resolution. Applications include fax machines, game systems, a variety of mark readers and other automation equipment requiring document scanners.

2.0 Key Features

- · Light source, lens and sensor are integrated into a single module
- 11.8dpm resolution, 216mm total scanning length (2592 pixels long)
- Two independent analog outputs (split into two sections of 1248 pixels and 1344 pixels)
- Up to 270µsec/line scanning speed with red light source
- Wide dynamic range
- Red LED light source
- Compact size ≅ 14mm x 19mm x 232mm
- Low power
- Light weight

3.0 Functional Description

The AMIS-710324-A4 imaging array consists of 27 sensors, AMIS-720321 (PI3021), produced by AMI Semiconductor. The sensor is a monolithic chip with an array of 96 photo sensing elements, of which 27 are cascaded to provide 2592 photo-detectors. Additionally, these chips give the users the readout flexibility in selecting their desired data format. These cascaded chips are segregated into two electrically independent sections of 13 chips and 14 chips, but they are still contiguously aligned in a single row, see Figure 1 (the module's block diagram). This configuration lends itself to a positional stream of video pixels, whether they are read in parallel or sequentially from the two output ports.

Each chip contains a set of multiplex switches, and a digital shift register to control the chips sequential readout. Additionally, the chips contain a chip selection switch that is interrogated in a sequence as each predecessor chip completes its scanning process. Since this module has two output ports from two independently controlled sections of chips, the users are required to enter a set of control clocks and power into each section through the two provided connectors located on each end of the module.



AMIS-710324-A4: 300dpi CIS Module

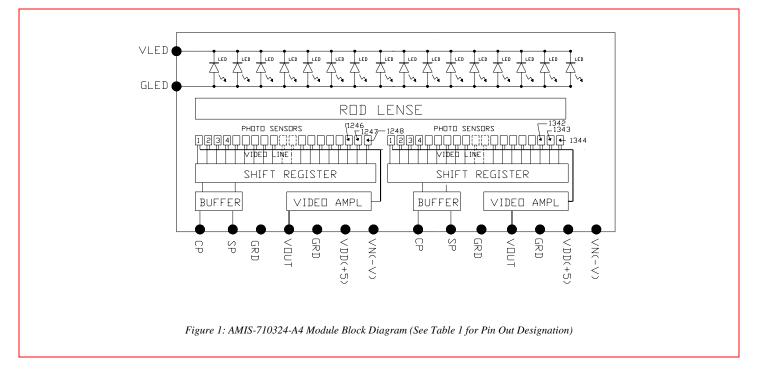
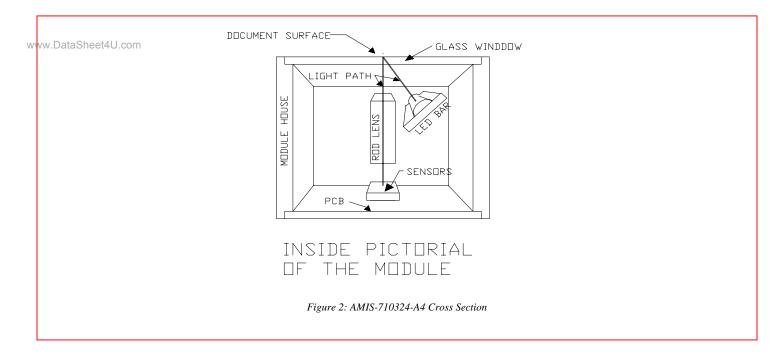


Figure 2 depicts a cross sectional pictorial of the module. Mounted in the module is a one-to-one graded indexed micro lens array that focuses the scanned documents' image onto the chip's sensing line. The sensing line is located along the module's sensor axis, known as the read line. These photon images are transformed into proportional video charges and processed by two on-board amplifiers. The video signal from the amplifier transmits a sequential stream of video pixels to the video output pin of the AMIS-710324-A4 module. Also mounted in the housing is a LED light source. Figure 2 shows the LED bar and its illumination path. The path traces the ray from the LED and is reflected from the document and focused through the ROD lens and onto the sensors. All these components are housed in a small plastic housing with a cover glass. The cover glass serves as a window with the outside surface as the focal point for the image on the document. It also serves to protect the imaging array, the micro lens assembly and the LED light source from dust.





4.0 I/O Designation

There are two connectors located at the ends of the modules. The outline of the module in Figure 5 of the mechanical section illustrates these connector locations. With the module window facing down on a flat surface and with the viewer looking down on the backside of the module, the connectors are located on each end of the module with their pins pointing toward the viewer. The connectors for Section 1 have 12 pins and are located on the right-hand side. The part number is JAE IL-Z-12P-S125L3-E. Its pin numbers and designations are listed in Table 1.

| Table 1: Pin Configuration for Section 1 Connector | | | | |
|--|--------------|---------------------------------|--|--|
| Pin Number | Symbol | Names and Functions | | |
| 1 | Vout1 | Analog video output | | |
| 2 | Gnd | Ground; 0V | | |
| 3 | Vdd (+5V) | Positive power supply | | |
| 4 | Vn (-5V) | Negative power supply | | |
| 5 | Gnd | Ground; 0V | | |
| 6 | SP1 | Shift register SP | | |
| 7 | Gnd | Ground; 0V | | |
| 8 | CP | Sampling clock pulse | | |
| 9 | GLED | Ground for the light source; 0V | | |
| 10 | VLED | Supply for the light source | | |
| 11 | LED (future) | Supply for future LED source | | |
| 12 | LED (future) | Supply for future LED source | | |

The connector for Section 2 has eight pins and is located on the left-hand side. The part number is JAE IL-Z-8P-S125L3-E. The pin numbers and designations for the connector are listed in Table 2.

Table 2: Pin Configuration for Section 2 Connector

| Pin Number | Symbol Names and Functions | | | | |
|------------------------------|----------------------------|-----------------------|--|--|--|
| 1 | Vout2 | Analog video output | | | |
| 2 | Gnd | Gnd Ground; 0V | | | |
| 3 | Vdd (+5V) | Positive power supply | | | |
| 4 | Vn (-5V) | Negative power supply | | | |
| 5 | Gnd | Ground; 0V | | | |
| 6 | SP2 | Shift register SP | | | |
| 7 | Gnd | Ground; 0V | | | |
| www.DataShe 8 t4U.com | CP | Sampling clock pulse | | | |



5.0 Absolute Maximum Rating

Table 3: Absolute Maximum Rating

| Parameter | Symbols | Maximum Rating | Units |
|--------------------------------|---------|----------------|-------|
| Power supply voltage | Vdd | 7 | V |
| | Idd | 70 | mA |
| | Vn | -15 | V |
| | In | 20 | mA |
| | VLED | 6.0 | V |
| | ILED | 0.65 | A |
| Input clock pulse (high level) | Vih | Vdd +.5 | V |
| Input clock pulse (low level) | Vil | -0.5 | V |

Note: These are the absolute maximums and are not to be used in prolonged operation.

6.0 Operating Environment

| Table 4: Operating Environment | | | | | | |
|--------------------------------|---------|----------------|-------|--|--|--|
| Parameter | Symbols | Maximum Rating | Units | | | |
| Operating temperature | Тор | 0 to 50 | °C | | | |
| Operating humidity | Нор | 10 to 85 | % | | | |
| Storage temperature | Tstg | -25 to +75 | Č | | | |
| Storage humidity | Hstg | 5 to 95 | % | | | |

7.0 Electro-Optical Characteristics at 25°C

Table: Electro-Optical Characteristics at 25°C

| Parameter | Symbol | Parameter | Units | Note |
|---|---------------------|-----------|----------|--|
| Total number of photo detectors | | 2592 | Elements | The sum of both sections |
| Number of detectors in Section 1 | | 1248 | Elements | |
| Number of detectors in Section 2 | | 1344 | Elements | |
| Pixel-to-pixel-spacing | | 84.7 | μm | |
| Line scanning rate | Tint ⁽¹⁾ | 270 | μsec | @ 5.0MHz clock frequency |
| Clock frequency ⁽²⁾ | f | 5.0 | MHz | |
| Bright output voltage ⁽³⁾ | Vpavg | 1.0 | V | |
| Bright output non-uniformity ⁽⁴⁾ | Up | <+/-30 | % | |
| Adjacent pixel non-uniformity ⁽⁵⁾ | Uadj | <25 | % | |
| Dark non-uniformity ⁽⁶⁾ | Ud | <100 | mV | |
| Dark output voltage ⁽⁶⁾ | Vd | <150 | mV | Average dark level from the video reset level |
| Typical modulation transfer function ⁽⁷⁾ | MTF | 50 | % | |

Notes:

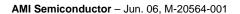
Tint: Line scanning rate or integration time. Tint is determined by the interval of two start pulses. The line scan time is determined by the longest array with both (1) Section 1 and 2 operating in parallel. The longest array is Section 2, with 1344 pixels, running at a 5MHz pixel rate.

(2)f: main clock frequency

Vpavg = $\sum Vp(n)/1248$ for section 1 and Vpavg = $\sum Vp(n)/1344$ for Section 2, where: Vp(n) is the peak value of any nth pixel in a give scan. (3)This level is factory adjusted with an internal potentiometer after setting the scan times to the minimum allowable for a fixed clock frequency. In this case, ~ 275µsec at 5MHz clock frequency. This value is then used as a reference to adjust the dark level and to call out the dark uniformity (see Note 6 on dark uniformity).

Up is defined as follows: Upmax = [(Vpmax - Vpavg) / Vpavg] x 100% or Upmin = [(Vpavg - Vpmin) / Vpavg] x 100% (4) where: Vpmax=the maximum value of the peak nth video pixel, Vp(n), and: Vpmin = the minimum value of the peak video n^{th} video pixel, Vp(n). Up = +/-30% is selected from the greater absolute value of Upmax of Upmin. If |Upmax| > |Upmin| then Up = +|Upmax| is selected, if |Upmin| > |Upmax| then Up = -|Upmin| is selected. In either case, $|Upmax| + |Upmin| \le 60\%$. (5) Upadj = MAX[$| (Vp(n) - Vp(n+I) | / Vp(n)] \times 100\%$

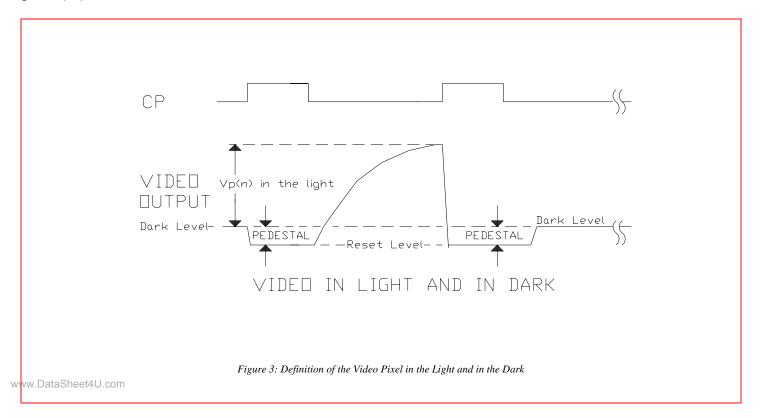
- Upadj is the non-uniformity percentage pixel to pixel (6)See Section 8.0 for discussion on dark uniformity, Ud.
- (7) See Section 9.0 on MTF Discussion and Graph.





8.0 Dark Uniformity, Ud

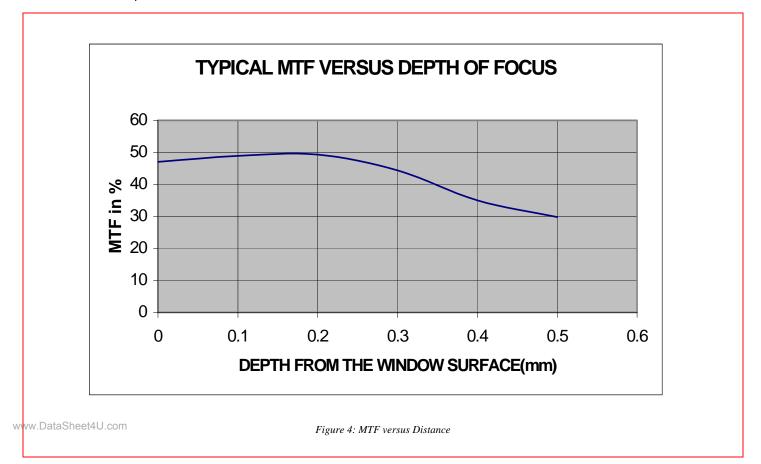
Figure 3 exemplifies the definitions of the terminology, which are used to explain the video signal characteristics. Dark uniformity is defined as Ud = Vdmax - Vdmin; where Vdmax and Vdmin are the maximum and minimum voltage of Vd, the average dark level of total pixels in the scan line when the LED light is turned off. Vd is measured from the reset level and the amplitude between the dark level and this reset level is called pedestal. The pedestal level is caused by the resetting operation of the pixel. Although the pedestal remains constant for a constant clock frequency, the reset level will vary from ground because the dark level, Vd, is factory adjusted to ground (0V).





9.0 MTF Graph and its Discussion

Figure 4 depicts MTF versus Distance. This graph essentially shows the working depth of focus. Since this module is a 300dpi module, with a pixel density of 300 pixels per inch, the MTF was measured with a 150dpi or a 75 line-pair per inch optical bar pattern. The tests were conducted at a pixel rate of 2.5MHz.



The effective algorithm used in the measurements is as described by the following equation:

 $\label{eq:MTF=} $ MTF={[Vp(n)+Vp(n+1)]/2-[Vp(n+2)+Vp(n+3)]/2}/{[Vp(n)+Vp(n+1)]/2+[Vp(n+2)+Vp(n+3)]/2} $ Where n is 1, 2,2592^{th}, Vp(n) is the signal amplitude of the nth pixel. $ MTF={[Vp(n)+Vp(n+2)+Vp(n+3)]/2} $ MTF={[Vp(n)+Vp(n+1)]/2+[Vp(n+2)+Vp(n+3)]/2} $ MTF={[Vp(n)+Vp(n+1)]/2+[Vp(n+2)+Vp(n+3)]/2} $ MTF={[Vp(n)+Vp(n+1)]/2+[Vp(n+2)+Vp(n+3)]/2} $ MTF={[Vp(n)+Vp(n+1)]/2+[Vp(n+2)+Vp(n+3)]/2} $ MTF={[Vp(n)+Vp(n+2)+Vp(n+3)]/2} $ MTF={[Vp(n)+Vp(n+2)+Vp(n+3)]/2} $ MTF={[Vp(n)+Vp(n+3)]/2} $ MTF={[Vp($

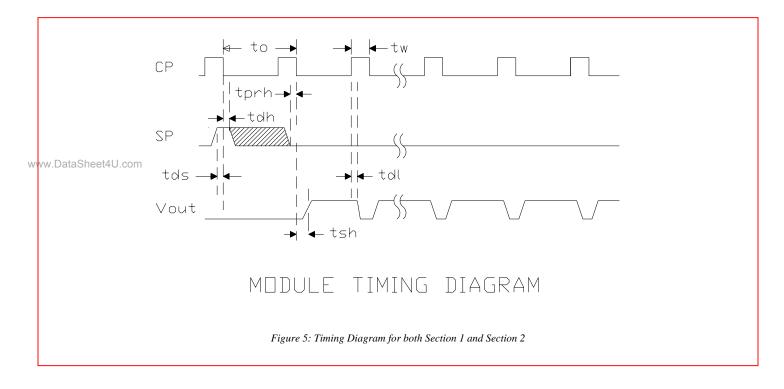


10.0 Recommended Operating Conditions (25°C)

Table 5: Recommended Operating Conditions (25°C) ltem Symbol Min. Mean Max. Units Power supply Vdd 4.5 5.0 5.5 V -4.5 V Vn. -5 -12 VLED 5.0 5.5 ٧ Idd (1&2) 35 55 ma 6.0 10.0 lvn (1&2) ma ILED 460 600 ma Input voltage at digital high Vih Vdd-1.0 Vdd-.5 Vdd ٧ Input voltage at digital low Vil V 0 0.8 Clock frequency f 5.5 MHz Clock pulse high duty cycle 25 % 50 Clock pulse high duration ns Integration time Tint(1) 0.270 5.0 ms Operating temperature Top 25 50 °C

11.0 Switching Characteristics (25°C)

The timing diagram for both arrays Section 1 and Section 2, are shown in Figure 5.



The switching characteristics for the I/O clocks are labeled symbolic acronyms for each corresponding clock's switching edges. The corresponding times for these symbols are given in Table 6.

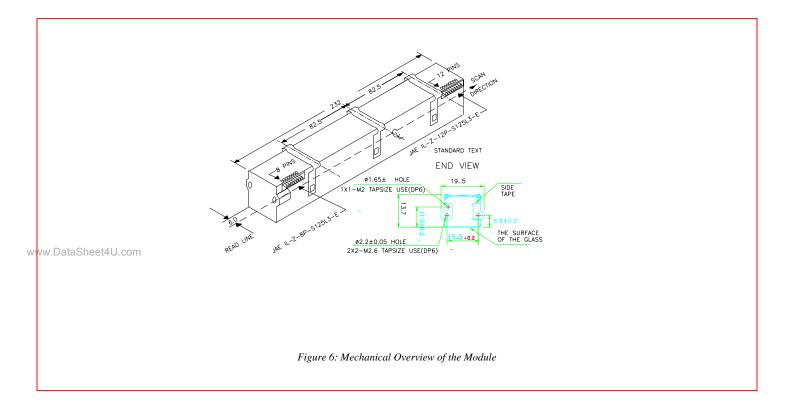


Table 6: Symbol Definitions for the Timing Diagram

| ltem | Symbol | Min. | Тур. | Max. | Units |
|------------------------------|--------|------|------|------|-------|
| Clock cycle time | to | 0.20 | | 4.0 | μs |
| Clock pulse width | tw | 50 | | | ns |
| Clock duty cycle | | 25 | | 75 | % |
| Prohibit crossing time of SP | tprh | 15 | | | ns |
| Data setup time | tds | 20 | | | ns |
| Data hold time | tdh | 20 | | | ns |
| Signal delay time | tdl | 50 | | | ns |
| Signal settling time | tsh | 120 | | | ns |

12.0 AMIS-710324-A4 Module and its Mechanical Dimensions

Figure 6 is an overview drawing of the module. If a detailed drawing is desired, especially for a design in application, a full size drawing is available upon request.





13.0 Company or Product Inquiries

For more information about AMI Semiconductor, our technology and our product, visit our Web site at: http://www.amis.com

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